TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG17FU

Schmitt Buffer

Features

• High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$

at V_{CC} = 3.0 V

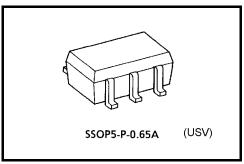
• High-speed operation: t_{pd} = 2.4 ns (typ.)

at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

• Operating voltage range: V_{CC} = 0.9~3.6 V

• 5.5-V tolerant inputs.

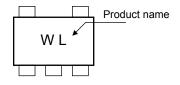
• 3.6-V power down protection output.

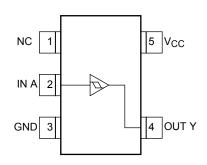


Weight: 0.006 g (typ.)

Marking

Pin Assignment (top view)





Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit				
Power supply voltage	V _{CC} -0.5~4.6		V				
DC input voltage	V _{IN}	-0.5~7.0	V				
DC output voltage	V	−0.5~ 4.6 (Note 1)	V				
DC output voltage	V _{OUT}	-0.5~ V _{CC} + 0.5 (Note 2)	V				
Input diode current	I _{IK}	-20	mA				
Output diode current	lok	-20 (Note 3)	mA				
DC output current	lout	±25	mA				
DC V _{CC} /ground current	Icc	±50	mA				
Power dissipation	PD	200	mW				
Storage temperature	T _{stg}	-65~150	°C				

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

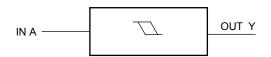
Note 1: $V_{CC} = 0V$

Note 2: High or Low State. I_{OUT} abusolute maximum rating must be observed.

Note 3: V_{OUT} < GND

IEC Logic Symbol

Truth Table



Α	Υ
L	L
Н	Н

Operating Range

Characteristics	Symbol	Value	Unit	
Power supply voltage	V _{CC}	. 0.9~3.6	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V	0~3.6 (Note 4)		
	Vout	0~V _{CC} (Note 5)	V	
Output Current		±8.0 (Note 6)		
	loh/lot	±4.0 (Note 7)		
		±3.0 (Note 8)	m ^	
		±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T _{opr}	-40~85	°C	

Note 4: $V_{CC} = 0.0 \text{ V}$

Note 5: High or Low state

Note 6: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 7: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 8: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 9: V_{CC} = 1.4~1.6 V

Note 10: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 11: $V_{CC} = 0.9 \text{ V}$

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Electrical Characteristics

DC Characteristics

Characteristics S		Symbol Test Condition		Ta = 25°C			Ta = -40~85°C		Unit		
		Symbol	1651	rest Condition		Min	Тур.	Max	Min	Max	Offic
Uink lavel					_	_	0.73	_	0.80	-	
					_	_	0.86	_	0.93		
	.,			1.4	_	_	1.07	_	1.12		
	High level	V _P			1.65	_	_	1.23	_	1.25	
					2.3	_	_	1.66	_	1.68	V
Threshold voltage					3.0	_	_	2.14	_	2.15	
Threshold voltage					0.9	0.18	_	_	0.07	_	
					1.1	0.26	_	_	0.18	_	
	11	.,,			1.4	0.36	_	_	0.31		
	Low level	V _N		_	1.65	0.45	_	_	0.41		
						0.69	_	_	0.64		
					3.0	0.96	_	_	0.91		
					0.9	0.20	_	0.38	0.15	0.53	
					1.1	0.25		0.41	0.21	0.53	
Llyotoropia va	ltaga	V.			1.4	0.35		0.48	0.34	0.57	.,
Hysteresis vo	oitage	V _H	_		1.65	0.42		0.56	0.40	0.60	V
						0.60		0.74	0.61	0.76	
					3.0	0.79		0.93	0.80	0.94	
		Vон	$V_{IN} = V_{IH}$	I _{OH} =-0.02 mA	0.9	0.75			0.75		V
				$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
	High level			I _{OH} = -1.7 mA	1.4~1.6	V _{CC} × 0.75			V _{CC} × 0.75		
				$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45	_	
				$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0	_	_	2.0	_	
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	_	2.48	_	
				$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	
				I _{OL} = 0.3 mA	1.1~1.3	_	_	V _{CC} × 0.25	_	V _{CC} × 0.25	
Low level	V _{OL} V	$V_{IN} = V_{IL}$	I _{OL} = 1.7 mA	1.4~1.6	_	—	V _{CC} × 0.25	_	V _{CC} × 0.25		
				I _{OL} = 3.0 mA	1.65~ 1.95	_	—	0.45	_	0.45	
				$I_{OL} = 4.0 \text{ mA}$	2.3~2.7	_	_	0.4	—	0.4	
				$I_{OL} = 8.0 \text{ mA}$	3.0~3.6	_	_	0.4	—	0.4	
Input leakage curre	ent	I _{IN}	V _{IN} = 0~5	.5V	0~3.6	_	_	±0.1	—	±1.0	μΑ
Power off leakage current I _C		l _{OFF}	V _{IN} = 0~5 V _{OUT} = 0~	V _{IN} = 0~5.5V V _{OUT} = 0~3.6V		_	_	1.0	_	10.0	μА
Quiescent supply current		Icc	$V_{IN} = V_{CC}$	V _{IN} = V _{CC} or GND		_		1.0	_	10.0	μΑ

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics			V _{CC} (V)	Min	Тур.	Max	Min	Max	Ullit
		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	27.3	_	_	_	
			1.1~1.3		13.0	22.6	1.0	35.9	
			1.4~1.6	_	7.5	10.5	1.0	11.3	ns
			1.65~ 1.95		6.0	7.8	1.0	8.2	
			2.3~2.7	_	4.3	5.4	1.0	5.8	
			3.0~3.6	_	3.5	4.4	1.0	4.6	
	t _P LH t _P HL	C_L = 15 pF, R_L = 1 M Ω	0.9	_	29.5	_	_	—	
			1.1~1.3	_	14.3	25.1	1.0	41.8	
			1.4~1.6	_	8.0	11.5	1.0	12.6	
Propagation delay time			1.65~ 1.95		6.3	8.4	1.0	8.7	
			2.3~2.7	_	4.6	5.7	1.0	6.1	
			3.0~3.6	_	3.7	4.6	1.0	5.0	
		C_L = 30 pF, R_L = 1 M Ω	0.9	_	40.5	_	_	—	
			1.1~1.3	_	19.6	35.7	1.0	58.1	
			1.4~1.6	_	10.7	15.8	1.0	17.6	
			1.65~ 1.95		7.8	10.7	1.0	11.7	
			2.3~2.7	_	5.4	6.9	1.0	8.1	
			3.0~3.6	_	4.3	5.2	1.0	6.1	
Input capacitance	C _{IN}	_	3.6	_	3	-	_	_	pF
Power dissipation capacitance	C _{PD}	(Note 12)	0.9 ~ 3.6	-	7		_	_	pF

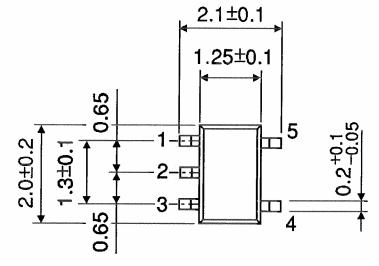
Note 12: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

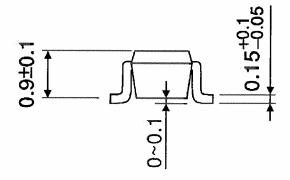
Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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